

Using Macro commands to erase and program Flash EEPROM

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In BDM software version 3.1 for parallel port and 4.1 for serial port, macro commands are incorporated to allow users to erase and program flash EEPROM through macro file. In this way, users have the full control how they are going to perform the operation. This application note explains the use of these commands.

The idea behind the operations is to write codes that perform erase or program operation in assembly language. The compiled code is loaded in to the device internal RAM. The code is then executed to perform the required function. For erase operation, data is generally not needed, so that the assembly code does not interact with the BDM. However, the interaction between assembly code and BDM software is necessary for programming operation. The BDM needs to prepare data to be programmed from S19 file, load the data into device memory. Then the assembly code works on the data and programs it into device flash memory. Then it informs BDM software that programming is finished, and the programming outcome, i.e., either data is programmed successfully, or an error is encountered in the process. BDM can access this error information to inform user. Therefore, BDM needs to perform the following function:

1. Load the assembly code into device internal memory;
2. Depending the function performed, BDM software may need to prepare data for the assembly code;
3. Execute the assembly code;
4. Probe the outcome when the process is finished.

These procedure may be repeated until the end of the data file.

According to these requirements, the following commands are provided:

LOAD Load a file into device internal memory
ERASE Execute an erase assembly code
PROG Execute a program assembly code

The command formats are discussed in the following text.

LOAD

Command format

LOAD FILE_NAME

The full path may be necessary if the file is not in the directory where the BDM software starts. The file must be in S19 format, which may have S1 or S2 record. For example:

LOAD C:\PROGRAM\FEPROG.S19

Will load FEPROG.S19 into device memory. The file is loaded with the current setup, which include device, linear address or paged address, etc.

PROG

Command format

PROG FILE_NAME PROG_ADDR DATA_ADDR MASK

FILE_NAME: data file name in S19 format. For S2 record, BDM will send the long address in high word and low word. It is up to the program code to interpret the meaning of the address.

PROG_ADDR: The start address of the assembly code that performs the programming function (or other functions that require data).

DATA_ADDR: The address BDM uses to store information required by the assembly code. It must have the format below:

	ORG	\$2100	
Page	dc.w	0	; page
Address	dc.w	0	; start address in Flash
NumWords	dc.w	0	; number of words
ErrorFlag	dc.w	0	
DATA	dc.w	0	; max of 64 words start here

Page: memory where BDM stores the high word of the address. The page can be linear or paged. It will be zero if S1 record is used. The software accepts any kind of S-record. S-record can be mixed in one S19 file. It is up to the assembly program to interpret the contents of the address (paged address, linear address, or not-paged address).

Address: memory where BDM stores the low word of the address.

NumWords: memory where BDM stores the number of **bytes** of data.

ErrorFlag: memory where assembly code stores the error code for BDM software to read.

DATA: Start memory where data is stored. The total number of byte is indicated by NumWords.

MASK: a 16-bit mask value. This value is ANDed with the error code read back from device. If the result is not zero, a message will pop up to indicate that an error is encountered in programming. And programming function will stop here. If an error does not matter, a 0 mask can be used.

PROG_ADDR, DATA_ADDR, and MASK all must be in hex-decimal format.
The ORG directive in this case indicates that the DATA_ADDR should be 2100 hex.
The BDM will read the S19 file to be programmed line by line. It always tries to store even number of bytes into the device since the programming algorithm of some devices requires word format. Therefore, if a line contains even number of bytes, the whole data is sent to the device. If a line contains odd number of bytes, the last byte will not be sent. This byte will be combined with the next line if the addresses of the two lines are continuous. If the addresses are not continuous, only one byte is sent as the high byte of the word. The number of byte in this case is 1. The code may need to handle this value specially.

Example:
S110C03E0B30215DCC0030CD102B6B40CD38
S111C04B102C6940CC000CCD102D6B40180BCA
S110C06E00181813C32014B7463A6B40F6FB

The first line starts at address \$C03E, and contains odd number of data. Therefore, 0B30 215D CC00 30CD 102B 6B40 are first programmed. CD will be programmed next time. In the second line, the address starts at C04B. This is continuous address from the first line. So CD is combined with this line. CD10 2C69 40CC 000C CD10 2D6B 4018 are then programmed. The remaining 0B will be combined with the third line. The start address of the third line is C06E, which is not a continuous address from the second line. Thus, only one byte 0B is programmed the third time. The fourth time will send data start at address \$C06E.

Since BDM always sends even number of bytes each time except the last single byte in a continuous block, it is suggested that each data block start on even address.

ERASE

Command format
ERASE PROG_ADDR DATA_ADDR MASK

The PROG_ADDR, DATA_ADDR, and MASK all have the same means as those explained in the PROG command. The only difference is the format of the DATA_ADDR:

ErrorFlag	dc.w	0
-----------	------	---

Only ErrorFlag is present. No data is necessary for erasing.

Example

The following example uses very simple programs to illustrate the uses of the ERASE and PROG commands. The code is intended to run on 912B32. For other processor, the address must be changed accordingly.

The first program simulates the erase procedure. It contains a wait loop to delay for a short while. Then the code clears RAM locations from B00 to BFF to prepare for "programming". Thus the code is called MacWait.asm, which is listed in the following:

; MacWait.ASM: Simple program to simulate flash erase code

```

                                ORG    $0800        ; start of internal ram
MAIN:
                                ldd     #$FFFF        ; load counter
AGAIN:
                                subd    #1           ; decrement counter
                                bne     AGAIN
                                ldaa    #$80
                                staa    ErrorFlag+1
                                ldd     #0
                                ldx     #$b00
AGAINI
                                std     2,x+
                                dec     ErrorFlag+1
                                bne     AGAINI
                                ldaa    #1
                                staa    ErrorFlag+1
                                bgnd
                                ORG     $A00
ErrorFlag dc.w 0
                                END
```

Note that the code starts at memory \$800. The data for error flag is \$A00.

The next piece of code simulates the programming of flash EEPROM. It only stores the data in s19 file in RAM starting \$B00.

; MacTest.ASM: Simple program to simulate flash programming

```

                                ORG     $0800        ; start of internal ram
MAIN:
                                ldx     Address        ; Destination
                                ldy     #DATA         ; source
AGAIN:
                                ldaa    1,y+          ; get word & change point
                                staa    1,x+          ; store word & change point
                                dec     NumWords+1    ; decrement counter
                                bne     AGAIN
                                ldaa    #0
                                staa    ErrorFlag+1
```

```

                bgnd

                ORG    $A00
Page            dc.w    0                ; page
Address         dc.w    0                ; start address in Flash
NumWords        dc.w    0                ; number of words
ErrorFlag       dc.w    0
DATA            dc.w    0                ; max of 64 words start here

                END

```

As in code MacWait.asm , the code starts address \$800, and data starts at \$A00. Code then moves the data sent by BDM to other RAM locations.

Note: For both erase and program code, a BGND command must be placed at the end of the program for BDM to sense if the program execution is finished.

The Macro file for MacWait and MacProg is listed below:

; File Name: LOAD.MAC: Test to load and program S19 file using MACRO file

```

RESET
LOAD C:\Userdata\HC12BGND\MacTest\MacWait.S19
erase 0800 0a00 ffff

LOAD C:\Userdata\HC12BGND\MacTest\MacProg.S19
prog c:\userdata\hc12bgnd\MacTest\EMPTY.s19 0800 0a00 ffff

LOAD C:\Userdata\HC12BGND\MacTest\MacProg.S19
prog c:\userdata\hc12bgnd\MacTest\Test1.s19 0800 0a00 ffff

LOAD C:\Userdata\HC12BGND\MacTest\MacProg.S19
prog c:\userdata\hc12bgnd\MacTest\Test2.s19 0800 0a00 ffff

```

MacWait is executed only once. However, MacProg is executed three times, with different data file each time. The first one just shows the response of an empty data file. The other two files contain different formats of S19 records. Note that all these commands can be placed in one Mcaro file to be executed once. The BDM will interpret these commands one by one and execute each command interpreted.

Since a value of 1 is loaded in the ErrorFlag in MacWait.asm, an error is always encountered in simulating erase procedure. A window will pop up to show the error code. In order to avoid this pop-up window, use a 0 to replace the mask ffff to mask of any error.

Appendix

Assembly code example

The following assembly code programs D256 flash EEPROM. Note that this code only program page FF. For other pages, page register must be considered.

```

; flash program registers
FCLKDIV    equ    $100                ; clock divider
FSEC       equ    $101
FCNFG      equ    $103
FPROT      equ    $104                ; protection register
FSTAT      equ    $105                ; status register

```

```

FCMD      equ    $106      ; command register
; bit definition
CBEIF     equ    $80      ; command buffer empty
CCIF      equ    $40      ; command complete flag
PVIOL     equ    $20      ; protection violation
ACCERR    equ    $10      ; Access error occurred
BLANK     equ    $04      ;

* Flash/EEProm programming commands...
ERASE      equ    $40      ; erase
PROGRAM    equ    $20      ; Program word
ERVER      equ    $04      ; Erase verify
MASS      equ    $01      ; Mass erase

VERIFY     equ    $05      ; Verify erased
S_ERASE    equ    $40      ; Sector erase
M_ERASE    equ    $41      ; Mass erase
S_MOD      equ    $60      ; sector modify, EEPROM only

PPAGE      equ    $30

```

```

                org    $2000
; PC: start address of this code in internal RAM, = 2000
; X: points to destination in Flash
; PPAGE:
; NumWords: number of words to be programmed
; Address: start address in Flash to be programmed
; FCNFG: Block selection register
; FCLKDIV: clock divider, only need to init once for all programming

```

```

; SP: not used

```

```

; Y: points to data in internal RAM, always the same = #DATA

```

```

                movb   #$4a,FCLKDIV ; Clock divider
                ldy    #DATA        ; points to start data
                ldx    Address      ; point address in flash
                ldab   NumWords+1   ; init count, +1 since a word
                lsr    ; shift 1 bits in word
                bne    EvenBytes
                ldab   #1           ; only one byte
EvenBytes      stab   NumWords+1   ; store back
                stab   count        ; also store in temp count

ProgLoop:
                ldd    2,y+         ; get word & change point
                std    2,x+         ; store word & change point
                ldab   #PROGRAM     ; program command
                stab   FCMD         ; write to command register
                ldab   #CBEIF       ; / start command
                stab   FSTAT        ; \ by write 1 to CBEIF
                ldab   FSTAT        ; check status
                bitb   #PVIOL+ACCERR ;
                bne    ErrCmd       ; command error
                brclr  FSTAT,#CBEIF,* ; loop if command buffer empty
                dec    count        ; any more word?
                bne    ProgLoop     ; do again
                brclr  FSTAT,#CCIF,* ; loop till all CMDs finish

```

```

; start to verify
ldab    NumWords+1    ; get number of words
stab    count          ; save in count
ldx     Address        ; load start address
ldy     #DATA          ; load data pointer
VeriLoop ldd    2,y+    ; load data
        cpd    2,x+    ; same as programmed?
        bne    ErrProg ; error programming
        dec    count   ; decrease count
        bne    VeriLoop ; again if not done
        ldd    #0      ; clear error flag
        std    ErrorFlag
        bgnd
ErrCmd   ldd    #1      ; stop
        std    ErrorFlag ; program command error
        bgnd
ErrProg  ldd    #2      ; not programmed correctly
        std    ErrorFlag
        bgnd

        org    $2100
count    dc.w    0      ; temp counter

Page     dc.w    0      ; page
Address  dc.w    0      ; start address in Flash
NumWords dc.w    0      ; number of words
ErrorFlag dc.w    0
DATA     dc.w    0      ; max of 64 words start here

```

From the code segment, PROG_ADDR is 2000, and DATA_ADDR is 2102.

FERASE.ASM: Erase DP256 internal flash eeprom

* EEprom status bits...

```

CBIEF    equ    $80    ; command buffer empty
CCIF     equ    $40    ; command complete flag
PVIOL    equ    $20    ; protection violation
ACCERR   equ    $10    ; Access error occurred
BLANK    equ    $04    ;

```

* Flash/EEprom programming commands...

```

EVRFY    equ    $05    ; Verify erased
PRGRM    equ    $20    ; Program word
S_ERASE   equ    $40    ; Sector erase
M_ERASE   equ    $41    ; Mass erase
S_MOD     equ    $60    ; sector modify, EEprom only

```

```

REGBS    equ    $0000

```

```

#include dp256reg.asm

```

```

        org    $1000

```

```

        movb    #$4A,FCLKDIV ; set Flash clock divider
        lds     #$2000        ; set stack

```

```
; Erase Internal Flash EEPROM
; Receive high order address to determine which block to erase.
```

Bulk:

```
; jsr (RecvHi-UTL_START)+RAMSTRT ; get the flash block address
```

EraseAll:

```
    jsr    CLRERR                ; clear error flags if any
    clra                    ; bulk all, start with block 0
```

EraseLoop:

```
    psha                    ; save current block
    bsr    Erase              ; do block erase
    pula                    ; get block number back
    bcs    EraseErr;
    tsta                    ; check if block 0 erased
    bne    EraseLp1           ; skif not block 0
    bsr    F_SEC              ; if 0, reset security
```

EraseLp1:

```
    inca                    ; next block
    cmpa    #4                ; test if done
    bne    EraseLoop          ; loop for all blocks
    ldab    #$A5              ; load pass code
    bra    EraseEnd
```

EraseErr:

```
    ldab    #$80              ; load error code
```

EraseEnd

```
; jsr (SendByte-UTL_START)+RAMSTRT ; Send code
    bgnd
```

; flash block mass erase routine..

Erase:

```
    staa    FCNFG              ; set flash block, interrupts off
    coma                    ; change up for page compute
    anda    #$03              ; mask block bits
    lsla                    ; shift for page ID
    lsla                    ;
    oraa    #$30              ; pages = $30, $34, $38, $3c
    staa    PPAGE              ; set page
    ldaa    #PVIOL+ACCERR      ; clear old fail flags,if any
    staa    FSTAT              ;
```

Erase1:

```
    ldaa    FSTAT              ; check if command buffer ready
    bpl    Erase1              ; wait till buffer empty
    bita    #CCIF              ; test command done
    beq    Erase1              ; wait till last command complete
    std     $8000              ; write to page address
```

* perform erase...

```
    movb    #M_ERASE,FCMD      ; mass erase block
    ldaa    #CBIEF              ; start command
    staa    FSTAT              ;
```

Eralp2:

```
    ldab    FSTAT              ; check if error
    bitb    #PVIOL+ACCERR      ; test for error
    bne    EraseFail           ; if error, quit this one
    ldab    FSTAT              ; check if command buffer ready
    bpl    Eralp2              ; wait till buffer empty
```

```

        bitb    #CCIF                ; test command done
        beq     Eralp2               ; wait till last command complete

; here if part was erased successfully
ErasePass
        clc
        rts
; here if part cannot be erased
EraseFail
        sec
        rts

; clear error flags...
CLRERR:
        ldab    #PVIOL+ACCERR        ; clear old fail flags,if any
        clra                                ; prep for loop
CLRERRLP:
        staa    FCNFG                ; set block number
        stab    FSTAT                ; clear flags
        inca
        bita    #$04                ; test for done
        beq     CLRERRLP             ; loop if not
        rts

; DP256 version...
; REset security byte to valid value...
F_SEC:
        ldd     #$FFFE                ; program new security
        std     $FF0E                ;
        ldaa    #PRGRM               ; get command
        staa    FCMD
        ldaa    #CBIEF               ; start command
        staa    FSTAT                ;
F_SEC1:
        ldab    FSTAT                ; check if error
        bitb    #PVIOL+ACCERR        ; test for error
        bne     F_SECX                ; if error, quit this one
        ldab    FSTAT                ; get status again
        bpl     F_SEC1               ; wait till buffer empty
        bitb    #CCIF                ; test command done
        beq     F_SEC1               ; wait till last command complete
        clra
F_SECX:
        rts                            ; done

```